National Semiconductor

June 1999

LM3480
100 mA, SOT-23, Quasi Low-Dropout Linear Voltage Regulator

General Description

The LM3480 is an integrated linear voltage regulator. It features operation from an input as high as 30V and a guaranteed maximum dropout of 1.2V at the full 100 mA load. Standard packaging for the LM3480 is the 3-lead SuperSOT® package.

The 5, 12, and 15V members of the LM3480 series are intended as tiny alternatives to industry standard LM78LXX series and similar devices. The 1.2V quasi low dropout of LM3480 series devices makes them a nice fit in many applications where the 2 to 2.5V dropout of LM78LXX series devices precludes their (LM78LXX series devices) use.

The LM3480 series features a 3.3V member. The SOT packaging and quasi low dropout features of the LM3480 series converge in this device to provide a very nice, very tiny 3.3V, 100 mA bias supply that regulates directly off the system 5V±5% power supply.

Key Specifications

- 30V maximum input for operation
- 1.2V guaranteed maximum dropout over full load and temperature ranges
- 100 mA guaranteed minimum load current
- ±5% guaranteed output voltage tolerance over full load and temperature ranges
- −40 to +125˚C junction temperature range for operation

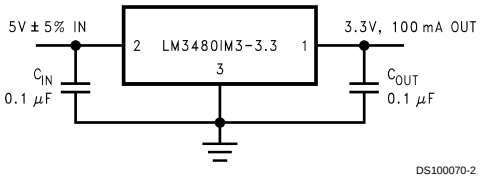
Features

- 3.3, 5, 12, and 15V versions available
- Packaged in the tiny 3-lead SuperSOT package

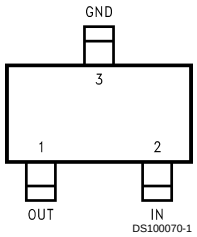
Applications

- Tiny alternative to LM78LXX series and similar devices
- Tiny 5V±5% to 3.3V, 100 mA converter
- Post regulator for switching DC/DC converter
- Bias supply for analog circuits

Typical Application Circuit



Connection Diagram



Top View
SOT-23 Package
3-Lead, Molded-Plastic Small-Outline Transistor (SOT) Package
Package Code MA03B (Note 1)

SuperSOT ® is a registered trademark of National Semiconductor.

Ordering Information

Output Voltage (V)	Order Number (Note 2)	Package Marking (Note 3)	Comments
3.3	LM3480IM3-3.3	L0A	250 Units on Tape and Reel
3.3	LM3480IM3X-3.3	L0A	3k Units on Tape and Reel
5	LM3480IM3-5.0	L0B	250 Units on Tape and Reel
5	LM3480IM3X-5.0	L0B	3k Units on Tape and Reel
12	LM3480IM3-12	L0C	250 Units on Tape and Reel
12	LM3480IM3X-12	L0C	3k Units on Tape and Reel
15	LM3480IM3-15	L0D	250 Units on Tape and Reel
15	LM3480IM3X-15	L0D	3k Units on Tape and Reel

Absolute Maximum Ratings (Note 4)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Input Voltage (IN to GND)	35V
Power Dissipation (Note 5)	333mW
Junction Temp. (Note 5)	+150˚C
Ambient Storage Temp.	−65 to +150˚C
Soldering Time, Temp. (Note 6)	
Wave	4 sec., 260˚C
Infrared	10 sec., 240˚C
Vapor Phase	75 sec., 219˚C
ESD (Note 7)	2kV

Operating Ratings (Note 4)

Max. Input Voltage (IN to GND)	30V
Junction Temp. (T_J)	−40 to +125˚C
Max. Power Dissipation (Note 8)	250mW

Electrical Characteristics

LM3480-3.3, LM3480-5.0

Typicals and limits appearing in normal type apply for $T_A = T_J = 25$˚C. Limits appearing in boldface type apply over the entire junction temperature range for operation, −40 to +125˚C. (Notes 9, 10, 11)

Nominal Output Voltage (V_{NOM})			3.3V		5.0V		Units
Symbol	**Parameter**	**Conditions**	**Typical**	**Limit**	**Typical**	**Limit**	
V_{OUT}	Output Voltage	$V_{IN} = V_{NOM} + 1.5V$, $1\ mA \le I_{OUT} \le 100\ mA$	3.30	 3.17 **3.14** 3.43 **3.46**	5.00	 4.80 **4.75** 5.20 **5.25**	V V(min) V(min) V(max) V(max)
ΔV_{OUT}	Line Regulation	$V_{NOM} + 1.5V \le V_{IN} \le 30V$, $I_{OUT} = 1\ mA$	10	 **25**	12	 **25**	mV mV(max)
ΔV_{OUT}	Load Regulation	$V_{IN} = V_{NOM} + 1.5V$, $10\ mA \le I_{OUT} \le 100\ mA$	20	 **40**	20	 **40**	mV mV(max)
I_{GND}	Ground Pin Current	$V_{NOM} + 1.5V \le V_{IN} \le 30V$, No Load	2	 **4**	2	 **4**	mA mA(max)
$V_{IN} - V_{OUT}$	Dropout Voltage	$I_{OUT} = 10\ mA$	0.7	 0.9 **1.0**	0.7	 0.9 **1.0**	V V(max) V(max)
		$I_{OUT} = 100\ mA$	0.9	 1.1 **1.2**	0.9	 1.1 **1.2**	V V(max) V(max)
e_n	Output Noise Voltage	$V_{IN} = 10V$, Bandwidth: 10 Hz to 100 kHz	100		150		μV_{rms}

LM3480-12, LM3480-15

Typicals and limits appearing in normal type apply for $T_A = T_J = 25^\circ C$. Limits appearing in boldface type apply over the entire junction temperature range for operation, −40 to +125˚C. (Notes 9, 10, 11)

Nominal Output Voltage (V_{NOM})			12V		15V		Units
Symbol	Parameter	Conditions	Typical	Limit	Typical	Limit	
V_{OUT}	Output Voltage	$V_{IN} = V_{NOM} + 1.5V$, $1\ mA \le I_{OUT} \le 100\ mA$	12.00	 11.52 **11.40** 12.48 **12.60**	15.00	 14.40 **14.25** 15.60 **15.75**	V V(min) V(min) V(max) V(max)
ΔV_{OUT}	Line Regulation	$V_{NOM} + 1.5V \le V_{IN} \le 30V$, $I_{OUT} = 1\ mA$	14	 **40**	16	 **40**	mV mV(max)
ΔV_{OUT}	Load Regulation	$V_{IN} = V_{NOM} + 1.5V$, $10\ mA \le I_{OUT} \le 100\ mA$	36	 **60**	45	 **75**	mV mV(max)
I_{GND}	Ground Pin Current	$V_{NOM} + 1.5V \le V_{IN} \le 30V$, No Load	2	 **4**	2	 **4**	mA mA(max)
V_{IN} - V_{OUT}	Dropout Voltage	$I_{OUT} = 10\ mA$	0.7	 0.9 **1.0**	0.7	 0.9 **1.0**	V V(max) V(max)
		$I_{OUT} = 100\ mA$	0.9	 1.1 **1.2**	0.9	 1.1 **1.2**	V V(max) V(max)
e_n	Output Noise Voltage	$V_{IN} = 10V$, Bandwidth: 10 Hz to 100 kHz	360		450		μV_{rms}

Note 1: The package code MA03B is internal to National Semiconductor Corporation and indicates a specific version of the SOT-23 package and associated mechanical drawings.

Note 2: The suffix "I" indicates the junction temperature range for operation is the industrial temperature range, −40 to +125˚C. The suffix "M3" indicates the die is packaged in the 3-lead SOT-23 package. The suffix "X" indicates the devices will be supplied in blocks of 3k units as opposed to blocks of 250 units.

Note 3: Because the entire part number does not fit on the SOT-23 package, the SOT-23 package is marked with this code instead of the part number.

Note 4: Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed performance limits. For guaranteed performance limits and associated test conditions, see the Electrical Characteristics tables.

Note 5: The Absolute Maximum power dissipation depends on the ambient temperature and can be calculated using $P = (T_J - T_A)/\theta_{JA}$ where T_J is the junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance. The 333 mW rating results from substituting the Absolute Maximum junction temperature, 150˚C, for T_J , 50˚C for T_A, and 300˚C/W for θ_{JA}. More power can be safely dissipated at lower ambient temperatures. Less power can be safely dissipated at higher ambient temperatures. The Absolute Maximum power dissipation can be increased by 3.33 mW for each ˚C below 50˚C ambient. It must be derated by 3.33 mW for each ˚C above 50˚C ambient. A θ_{JA} of 300˚C/W represents the worst-case condition of no heat sinking of the 3-lead plastic SOT-23 package. Heat sinking enables the safe dissipation of more power. The LM3480 actively limits its junction temperature to about 150˚C.

Note 6: Times shown are dwell times. Temperatures shown are dwell temperatures. For detailed information on soldering plastic small-outline packages, refer to the *Packaging Databook* available from National Semiconductor Corporation.

Note 7: For testing purposes, ESD was applied using the human-body model, a 100 pF capacitor discharged through a 1.5 kΩ resistor.

Note 8: As with the Absolute Maximum power dissipation, the maximum power dissipation for operation depends on the ambient temperature. The 250 mW rating appearing under Operating Ratings results from substituting the maximum junction temperature for operation, 125˚C, for T_J, 50˚C for T_A, and 300˚C/W for θ_{JA} in $P = (T_J - T_A)/\theta_{JA}$. More power can be dissipated at lower ambient temperatures. Less power can be dissipated at higher ambient temperatures. The maximum power dissipation for operation appearing under Operating Ratings can be increased by 3.33 mW for each ˚C below 50˚C ambient. It must be derated by 3.33 mW for each ˚C above 50˚C ambient. A θ_{JA} of 300˚C/W represents the worst-case condition of no heat sinking of the 3-lead plastic SOT-23 package. Heat sinking enables the dissipation of more power during operation.

Note 9: A typical is the center of characterization data taken with $T_A = T_J = 25^\circ C$. Typicals are not guaranteed.

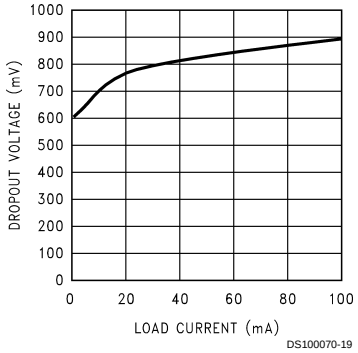
Note 10: All limits are guaranteed. All electrical characteristics having room-temperature limits are tested during production with $T_A = T_J = 25^\circ C$. All hot and cold limits are guaranteed by correlating the electrical characteristics to process and temperature variations and applying statistical process control.

Note 11: All voltages except dropout are with respect to the voltage at the GND pin.

Typical Performance Characteristics

Unless indicated otherwise, $V_{IN} = V_{NOM} + 1.5V$, $C_{IN} = 0.1\ \mu F$, $C_{OUT} = 0.1\ \mu F$, and T_A =25˚C.

Dropout Voltage vs Load Current



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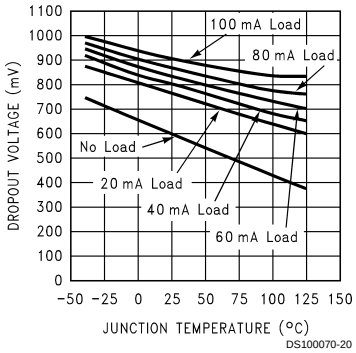
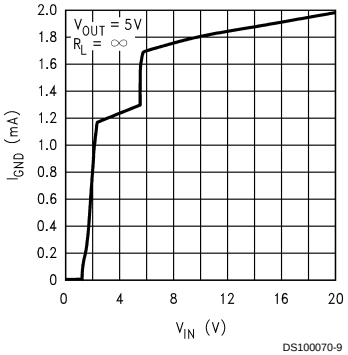
Dropout Voltage vs Junction Temperature



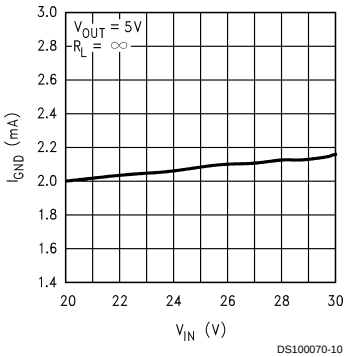
DS100070-20

Ground Pin Current vs Input Voltage



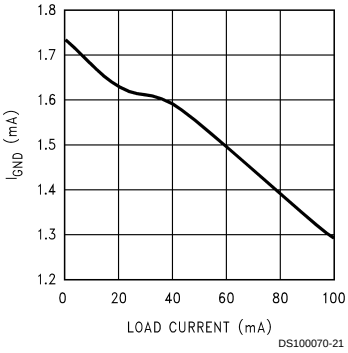
DS100070-9

Ground Pin Current vs Input Voltage



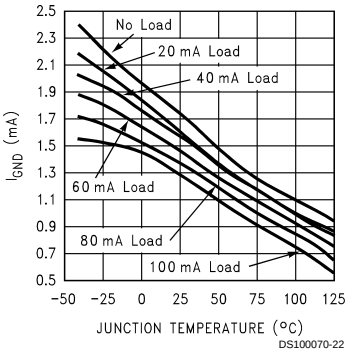
DS100070-10

Ground Pin Current vs Load Current



DS100070-21

Ground Pin Current vs Junction Temperature

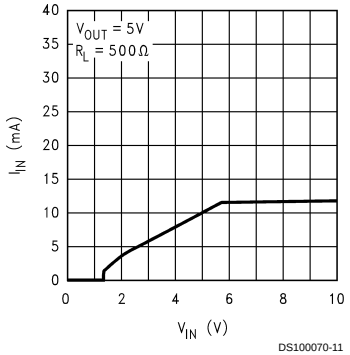


DS100070-22

Typical Performance Characteristics

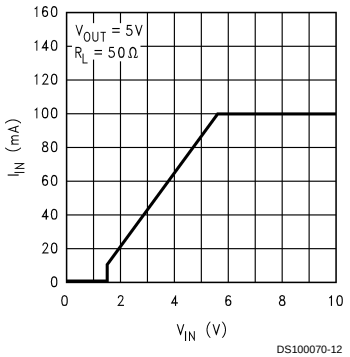
Unless indicated otherwise, $V_{IN} = V_{NOM} + 1.5V$, $C_{IN} = 0.1\ \mu F$, $C_{OUT} = 0.1\ \mu F$, and T_A =25˚C. (Continued)

Input Current vs Input Voltage



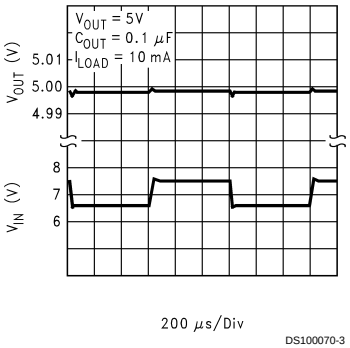
DS100070-11

Input Current vs Input Voltage



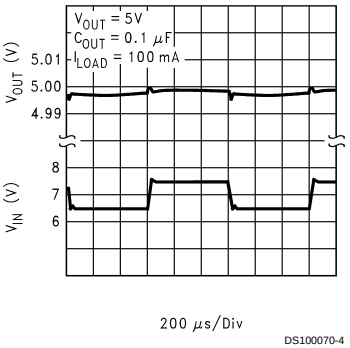
DS100070-12

Line Transient Response



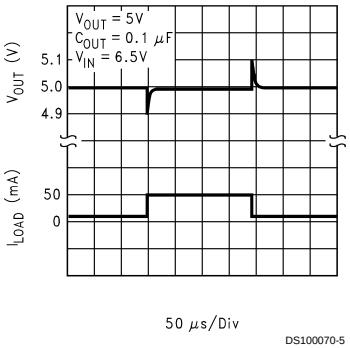
DS100070-3

Line Transient Response



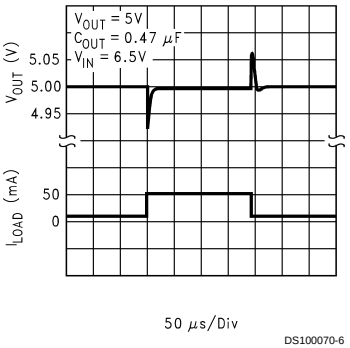
DS100070-4

Load Transient Response



DS100070-5

Load Transient Response

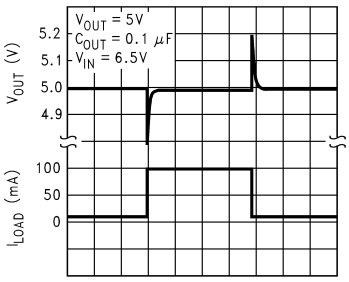


DS100070-6

Typical Performance Characteristics

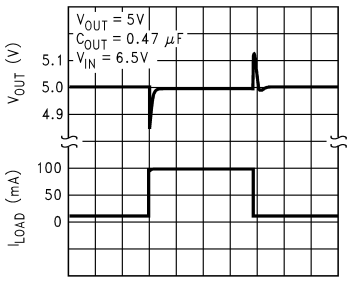
Unless indicated otherwise, $V_{IN} = V_{NOM} + 1.5V$, $C_{IN} = 0.1\ \mu F$, $C_{OUT} = 0.1\ \mu F$, and $T_A = 25^{\circ}C$. (Continued)

Load Transient Response



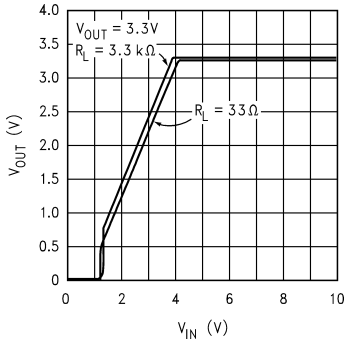
DS100070-7

Load Transient Response



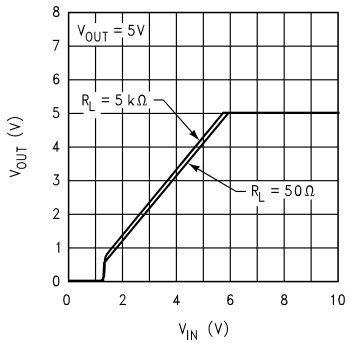
DS100070-8

Output Voltage vs Input Voltage



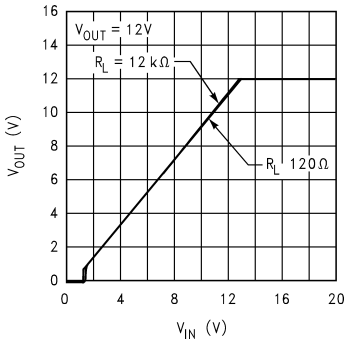
DS100070-13

Output Voltage vs Input Voltage



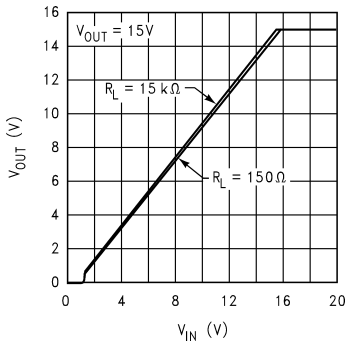
DS100070-14

Output Voltage vs Input Voltage



DS100070-15

Output Voltage vs Input Voltage

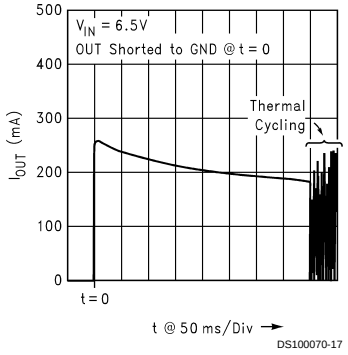


DS100070-16

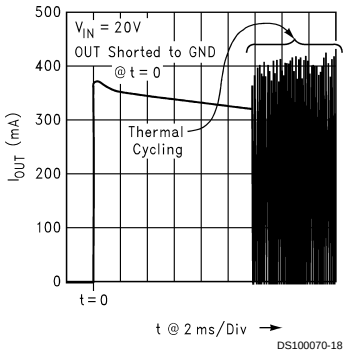
Typical Performance Characteristics

Unless indicated otherwise, $V_{IN} = V_{NOM} + 1.5V$, $C_{IN} = 0.1\ \mu F$, $C_{OUT} = 0.1\ \mu F$, and $T_A = 25^{\circ}C$. (Continued)

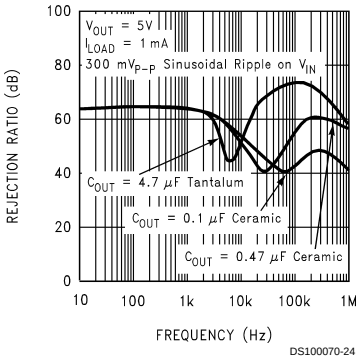
Output Short-Circuit Current



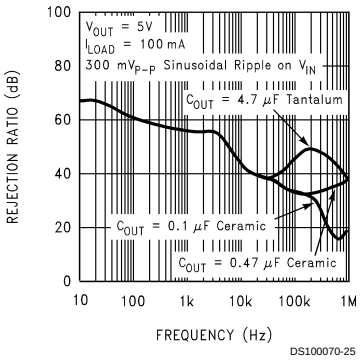
Output Short-Circuit Current



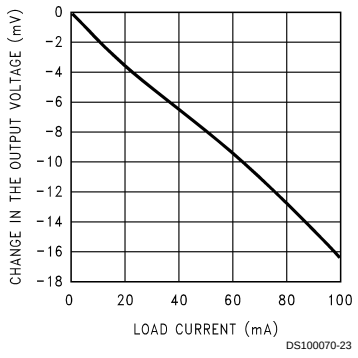
Power Supply Rejection Ratio



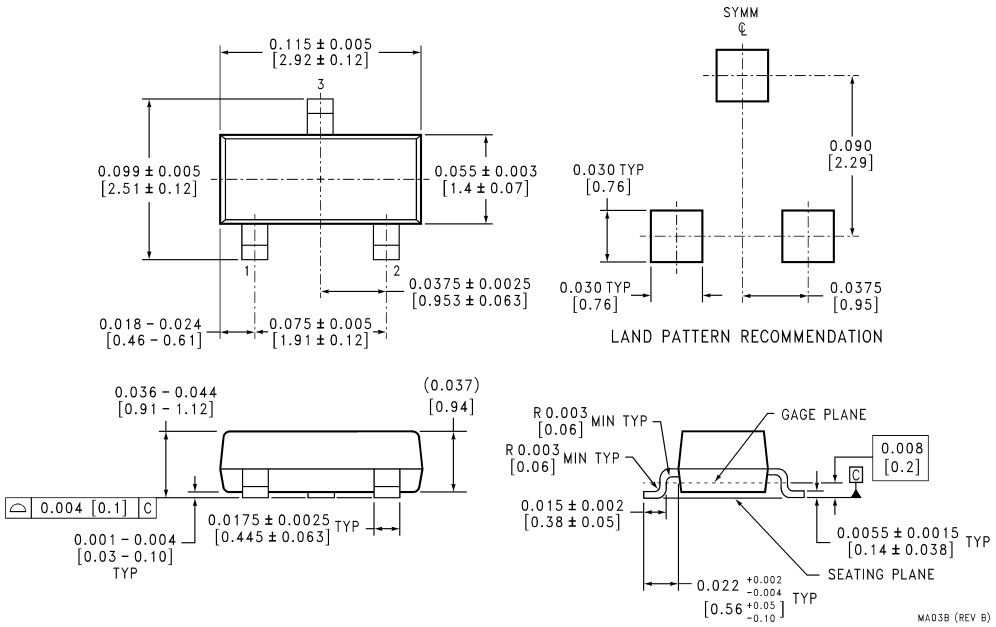
Power Supply Rejection Ratio



DC Load Regulation



Physical Dimensions inches (millimeters) unless otherwise noted



SOT-23 Package
3-Lead Small-Outline Package (M3)
For Ordering, Refer to Ordering Information Table
NS Package Number MA03B

LIFE SUPPORT POLICY

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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